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April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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## MOS FIELD EFFECT TRANSISTOR 2SK3993

## **SWITCHING N-CHANNEL POWER MOSFET**

#### **DESCRIPTION**

The 2SK3993 is N-channel MOS FET device that features a low on-state resistance and excellent switching characteristics, and designed for low voltage high current applications such as DC/DC converter with synchronous rectifier.

#### ORDERING INFORMATION

PART NUMBER	PACKAGE			
2SK3993	TO-251 (MP-3)			
2SK3993-ZK	TO-252 (MP-3ZK)			

#### **FEATURES**

- Low on-state resistance  $R_{DS(on)1}$  = 3.8 m $\Omega$  MAX. (Vgs = 10 V, ID = 32 A)
- Low Ciss: Ciss = 4770 pF TYP.
- 5 V drive available



ced Prodi ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (V <sub>GS</sub> = 0 V)	Voss 🔷	25	V
Gate to Source Voltage (VDS = 0 V)	Vgss	±20	V
Drain Current (DC) (Tc = 25°C)	ID(DC)	±64	Α
Drain Current (pulse) Note1	ID(pulse)	±256	Α
Total Power Dissipation (Tc = 25°C)	P <sub>T1</sub>	40	W
Total Power Dissipation	P <sub>T2</sub>	1.0	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	-55 to +150	°C
Single Avalanche Current Note2	las	41	Α
Single Avalanche Energy Note2	Eas	168	mJ

**Notes 1.** PW  $\leq$  10  $\mu$ s, Duty Cycle  $\leq$  1%

**2.** Starting T<sub>ch</sub> = 25°C, V<sub>DD</sub> = 12.5 V, R<sub>G</sub> = 25  $\Omega$ , V<sub>GS</sub> = 20  $\rightarrow$  0 V

(TO-252)



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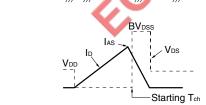
#### **ELECTRICAL CHARACTERISTICS (TA = 25°C)**

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V <sub>DS</sub> = 25 V, V <sub>GS</sub> = 0 V			10	μΑ
Gate Leakage Current	Igss	V <sub>GS</sub> = ±20 V, V <sub>DS</sub> = 0 V			±100	nA
Gate Cut-off Voltage	V <sub>GS(off)</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA	2.0	2.4	3.0	V
Forward Transfer Admittance Note	yfs	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 16 A	15			S
Drain to Source On-state Resistance Note	RDS(on)1	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 32 A		2.7	3.8	mΩ
	RDS(on)2	V <sub>GS</sub> = 5.0 V, I <sub>D</sub> = 16 A		4.1	7.8	mΩ
Input Capacitance	Ciss	V <sub>DS</sub> = 10 V		4770		pF
Output Capacitance	Coss	Ves = 0 V		1000		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		690		pF
Turn-on Delay Time	t <sub>d(on)</sub>	V <sub>DD</sub> = 12.5 V, I <sub>D</sub> = 32 A	×	27		ns
Rise Time	tr	Ves = 10 V	5	38		ns
Turn-off Delay Time	<b>t</b> d(off)	R <sub>G</sub> = 10 Ω	6	107		ns
Fall Time	tr			54		ns
Total Gate Charge	QG	V <sub>DD</sub> = 20 V		88		nC
Gate to Source Charge	Q <sub>G</sub> s	Ves = 10 V		16		nC
Gate to Drain Charge	Q <sub>GD</sub>	ID = 64 A		30		nC
Body Diode Forward Voltage Note	V <sub>F</sub> (S-D)	IF = 64 A, VGS = 0 V		0.91		V
Reverse Recovery Time	trr	IF = 64 A, VGS = 0 V		43		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/μs		52		nC

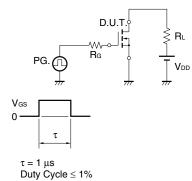
Note Pulsed

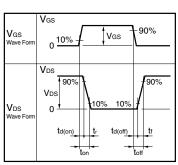
### **TEST CIRCUIT 1 AVALANCHE CAPABILITY**

# $V_{GS} = 20 \rightarrow 0 \text{ V}$



#### TEST CIRCUIT 2 SWITCHING TIME

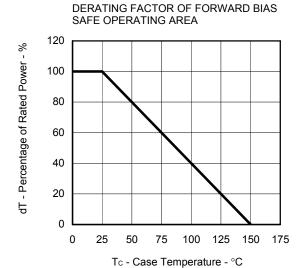




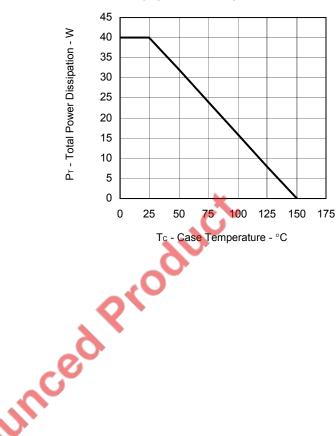
#### **TEST CIRCUIT 3 GATE CHARGE**



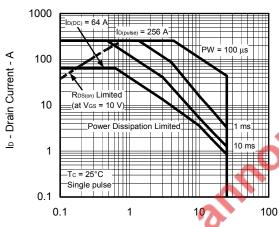
#### TYPICAL CHARACTERISTICS (TA = 25°C)



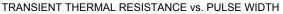
#### TOTAL POWER DISSIPATION vs. CASE TEMPERATURE

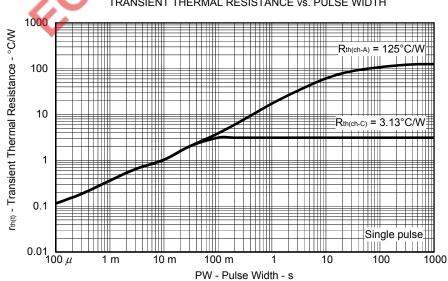


#### FORWARD BIAS SAFE OPERATING AREA







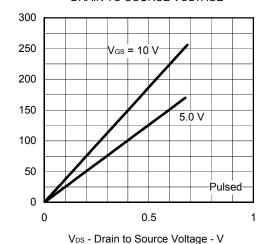


3

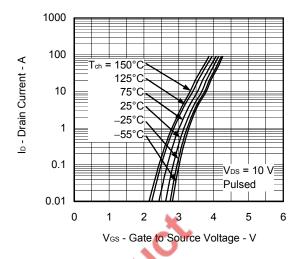
lo - Drain Current - A

VGS(off) - Gate Cut-off Voltage - V

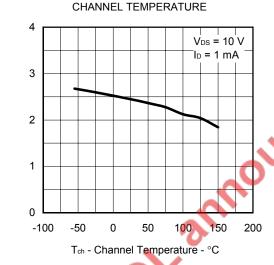
## DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



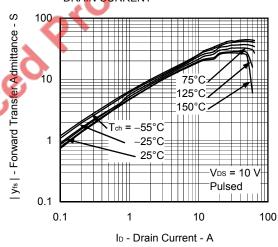
#### FORWARD TRANSFER CHARACTERISTICS



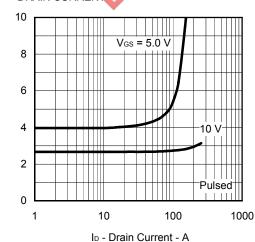
## GATE CUT-OFF VOLTAGE vs.



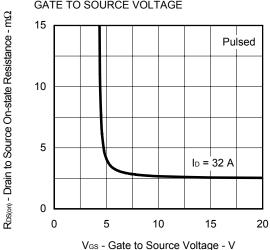
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



## DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE

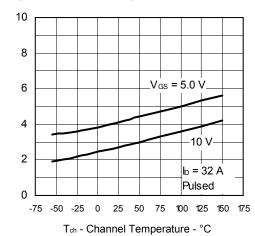


R<sub>DS(on)</sub> - Drain to Source On-state Resistance - mΩ

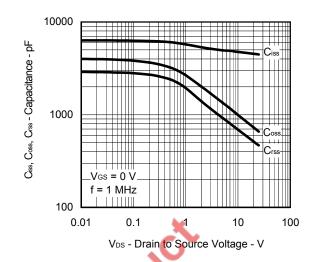


RDS(on) - Drain to Source On-state Resistance - m\Omega

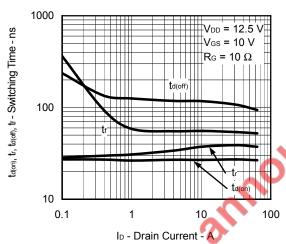
## DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



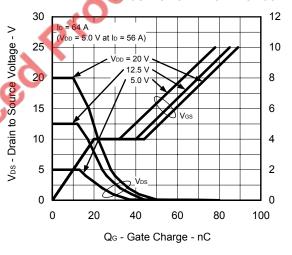
#### CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



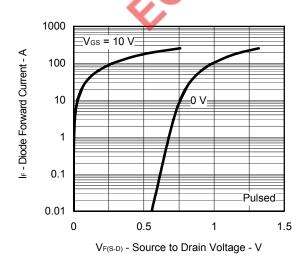
#### SWITCHING CHARACTERISTICS



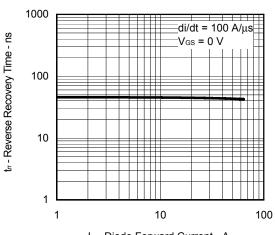
DYNAMIC INPUT/OUTPUT CHARACTERISTICS



#### SOURCE TO DRAIN DIODE FORWARD VOLTAGE



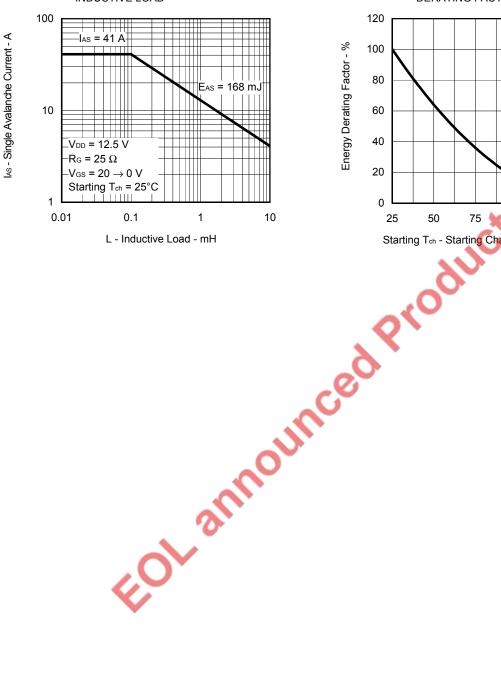
REVERSE RECOVERY TIME vs. DIODE FORWARD CURRENT



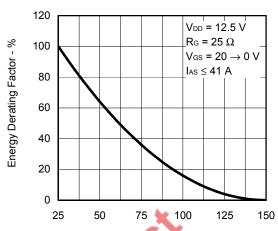
IF - Diode Forward Current - A

Ves - Gate to Source Voltage - V

#### SINGLE AVALANCHE CURRENT vs. INDUCTIVE LOAD



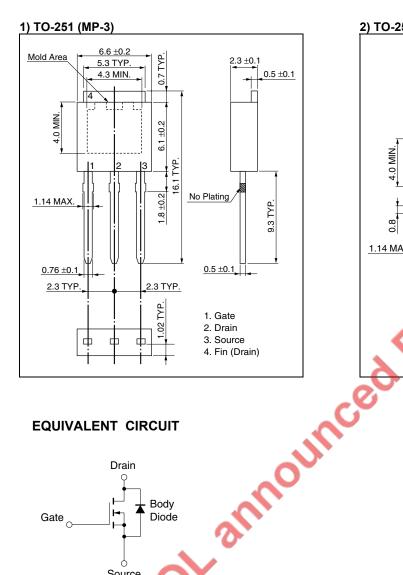
#### SINGLE AVALANCHE ENERGY **DERATING FACTOR**

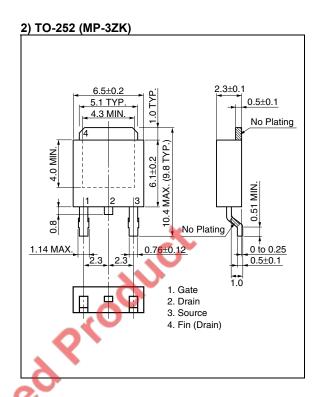


Starting Tch - Starting Channel Temperature - °C

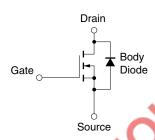


#### PACKAGE DRAWINGS (Unit: mm)





#### **EQUIVALENT CIRCUIT**



Remark Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.

> 7 Data Sheet D17322EJ2V0DS

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